

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE40P07S uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

● V_{DS} =-40V,I_D =-6.2A

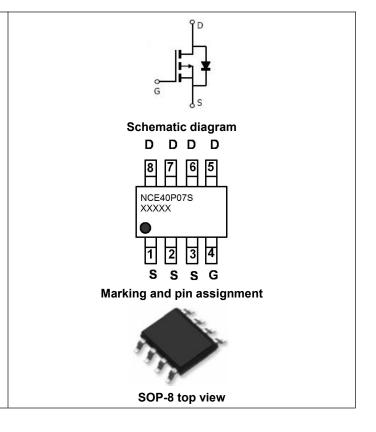
 $R_{DS(ON)}$ <25m Ω @ V_{GS} =-10V

 $R_{DS(ON)}$ <30m Ω @ V_{GS} =-4.5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- DC-DC converter



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE40P07S	NCE40P07S	SOP-8	Ø330mm	12mm	4000 units

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	-40	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	-6.2	Α
Drain Current-Continuous(T _C =100 °C)	I _D (100°C)	-4	Α
Pulsed Drain Current	I _{DM}	40	Α
Maximum Power Dissipation	P _D	2.5	W
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance ,Junction-to-Ambient ^(Note 2)	$R_{\theta JA}$	50	°C/W

Electrical Characteristics (T_A=25°Cunless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-40	-	-	V



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NCE40P07S

Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-40 V , V_{GS} =0 V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=-250\mu A$	-1.1	-1.7	-2.5	V
D : 0		V _{GS} =-10V, I _D =-5A	_	16	25	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-5A	-	21	30	mΩ
Forward Transconductance	g FS	V _{DS} =-5V,I _D =-5A	20	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	V 00V/V 0V	-	1750	-	PF
Output Capacitance	Coss	V_{DS} =-20V, V_{GS} =0V, F=1.0MHz	-	215	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.UIVIHZ	-	180	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	9	-	nS
Turn-on Rise Time	t _r	V_{DD} =-20 V , $,R_L$ =2 Ω	-	8	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10 V , R_{GEN} =3 Ω	-	28	-	nS
Turn-Off Fall Time	t _f		-	10	-	nS
Total Gate Charge	Qg	\/ - 20\/ - 54	-	24	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-20 V , I_{D} =-5 A , V_{GS} =-10 V	-	3.5	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} 10V	-	6	-	nC
Drain-Source Diode Characteristics			-			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-6A	-	-	1.2	V
Diode Forward Current (Note 2)	ls		-	-	-6.2	Α

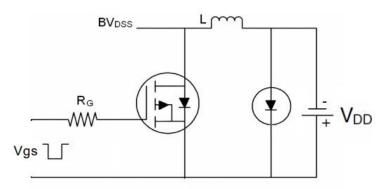
Notes:

- Repetitive Rating: Pulse width limited by maximum junction temperature.
 Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

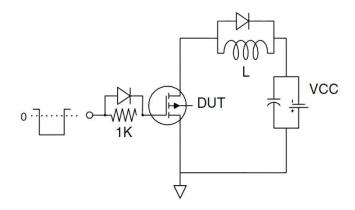


Test Circuit

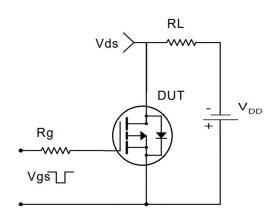
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

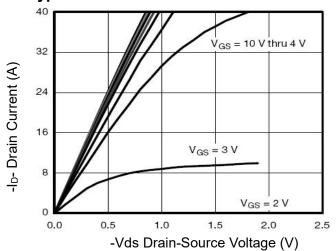


Figure 1 Output Characteristics

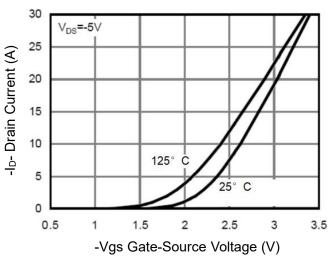


Figure 2 Transfer Characteristics

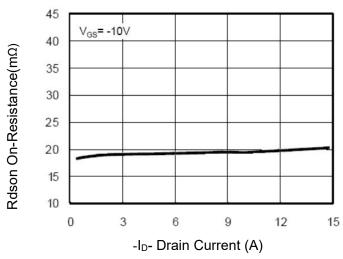


Figure 3 Rdson- Drain Current

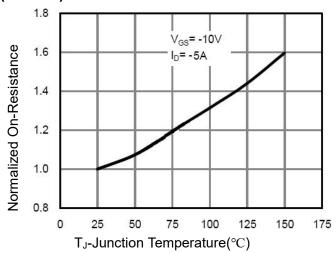


Figure 4 Rdson-Junction Temperature

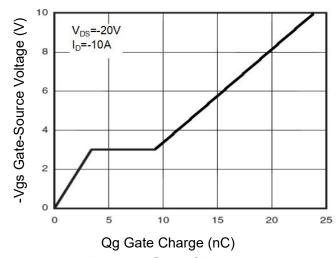


Figure 5 Gate Charge

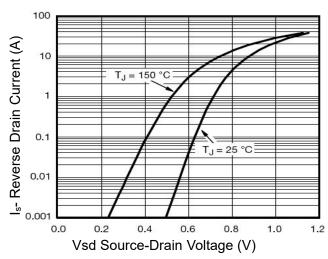


Figure 6 Source- Drain Diode Forward



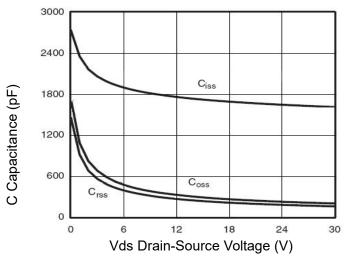


Figure 7 Capacitance vs Vds

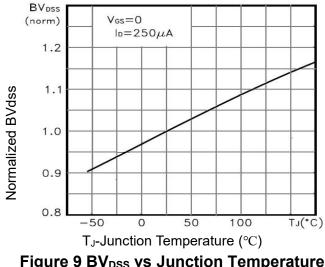


Figure 9 BV_{DSS} vs Junction Temperature

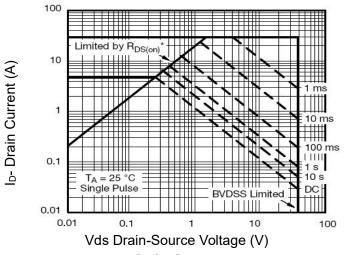


Figure 8 Safe Operation Area

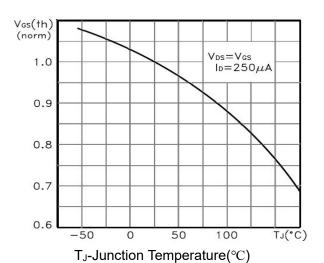


Figure 10 V_{GS(th)} vs Junction Temperature

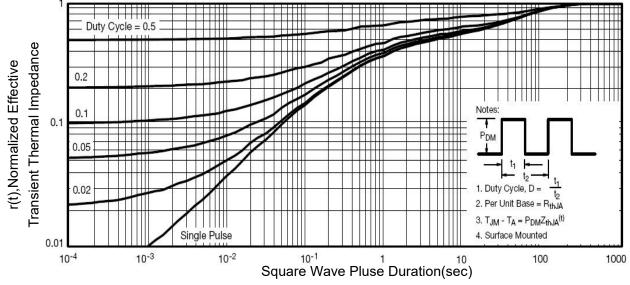
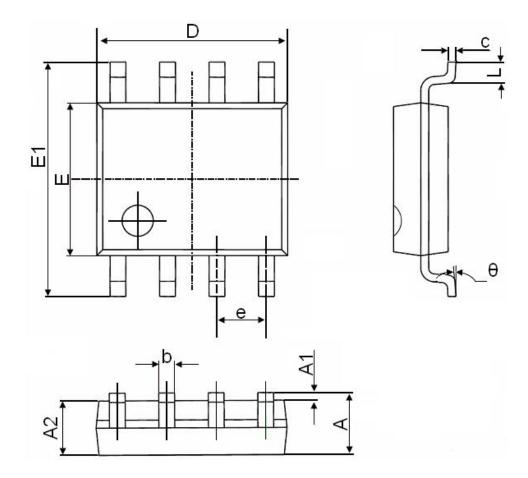


Figure 11 Normalized Maximum Transient Thermal Impedance



SOP-8 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270(BSC)		0.050(BSC)		
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	

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